

SN74AHCT138Q-Q1 Automotive 3-Line to 8-Line Decoders/Demultiplexers

1 Features

- Qualified for Automotive Applications
- EPIC (Enhanced-Performance Implanted CMOS) Process
- Inputs Are TTL-Voltage Compatible
- Designed Specifically for High-Speed Memory Decoders and Data-Transmission Systems
- Incorporates Three Enable Inputs to Simplify Cascading and/or Data Reception
- Latch-Up Performance Exceeds 250mA Per JESD 17
- ESD Protection Exceeds 2000V Per MIL-STD-883, Method 3015

2 Description

The SN74AHCT138Q 3-line to 8-line decoder/demultiplexer is designed to be used in high-performance memory-decoding and data-routing applications that require very short propagation-delay times. In high-performance memory systems, this decoder can be used to minimize the effects of system decoding. When employed with high-speed memories utilizing a fast enable circuit, the delay times of this decoder and the enable time of the memory usually are less than the typical access time of the memory. This means that the effective system delay introduced by the decoder is negligible.

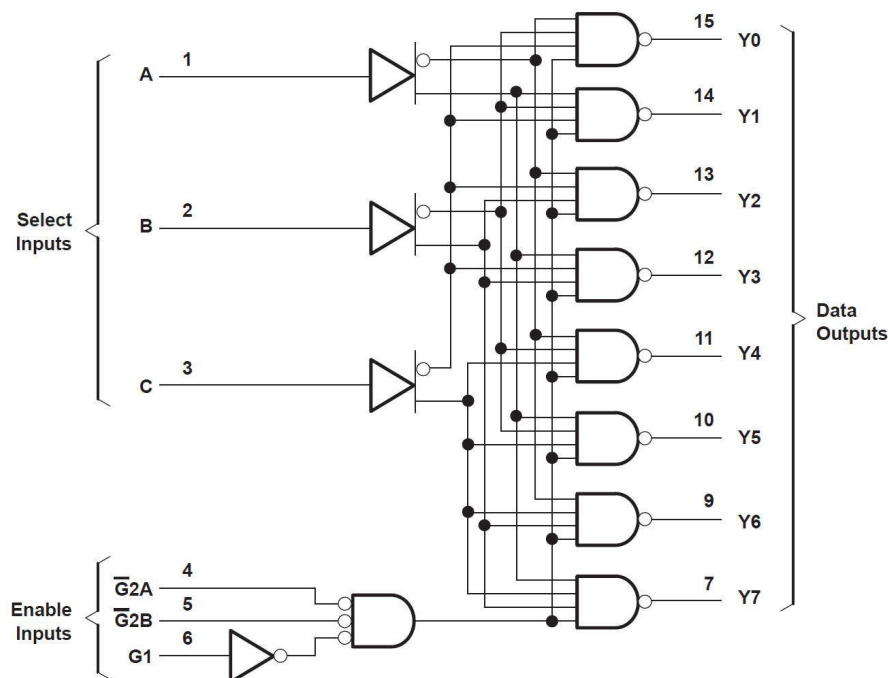
Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾	BODY SIZE ⁽³⁾
SN74AHCT138Q-Q1	BQB (WQFN, 16)	3.5mm x 2.5mm	3.5mm x 2.5mm
	D (SOIC, 16)	9.9mm x 6mm	9.9mm x 3.9mm
	PW (TSSOP, 16)	5.00mm x 6.4mm	5.00mm x 4.40mm

(1) For more information, see [Section 10](#).

(2) The package size (length x width) is a nominal value and includes pins, where applicable.

(3) The body size (length x width) is a nominal value and does not include pins.



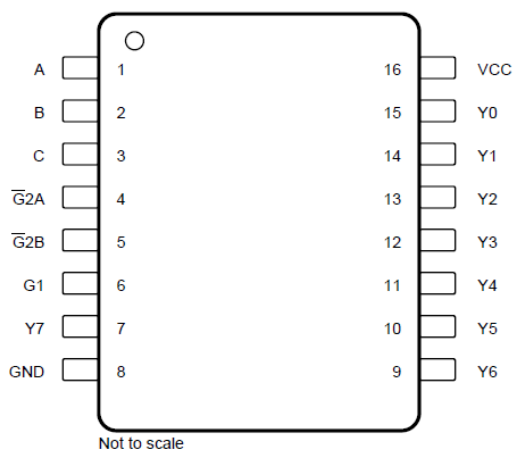
Logic Diagram (Positive Logic)



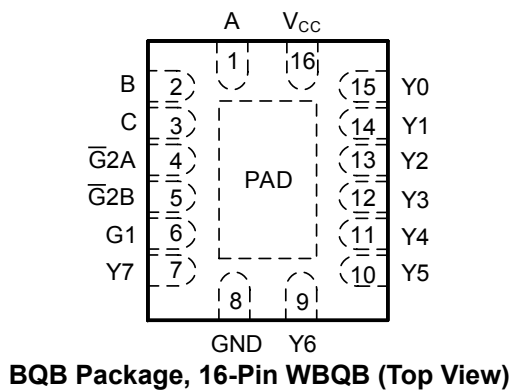
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3 Pin Configuration and Functions



D or PW Package, 16-Pin SOIC or TSSOP (Top View)



NAME	PIN	I/O ⁽¹⁾	DESCRIPTION
	SOIC, TSSOP, WQFN		
A	1	I	Select input A (least significant bit)
B	2	I	Select input B
C	3	I	Select input C (most significant bit)
$\overline{G}2A$	4	I	Active low enable A
$\overline{G}2B$	5	I	Active low enable B
G1	6	I	Active high enable
GND	8	—	Ground
NC	—	—	No internal connection
V _{CC}	16	—	Supply voltage
Y0	15	O	Output 0 (least significant bit)
Y1	14	O	Output 1
Y2	13	O	Output 2
Y3	12	O	Output 3
Y4	11	O	Output 4
Y5	10	O	Output 5
Y6	9	O	Output 6
Y7	7	O	Output 7 (most significant bit)
Thermal pad ⁽²⁾		The thermal pad can be connected to GND or left floating. Do not connect to any other signal or supply.	

(1) Signal Types: I = Input, O = Output, I/O = Input or Output, P = Power, G = Ground.

(2) WBQB package only.

4 Specifications

4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage range	−0.5	7	V
V _I	Input voltage range	−0.5	7	V
V _O	Output voltage range	−0.5V	V _{CC} + 0.5	V
I _{IK}	Input clamp current ⁽²⁾	V _I < 0	−20	mA
I _{OK}	Output clamp current ⁽²⁾	V _O < 0 or V _O > V _{CC}	±20	mA
I _O	Continuous output current	V _O = 0 to V _{CC}	±25	mA
	Continuous current through V _{CC} or GND		±75	mA
T _{stg}	Storage temperature	−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

4.2 ESD Ratings

	VALUE	UNIT
V _(ESD) Electrostatic discharge Human body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000	V

- (1) AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

4.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	MIN	MAX	UNIT
V _{CC} Supply voltage	4.5	5.5	V
V _{IH} High-level input voltage	2		V
V _{IL} Low-level input voltage		0.8	V
V _I Input voltage	0	5.5	V
V _O Output voltage	0	V _{CC}	V
I _{OH} High-level output current		−8	
I _{OL} Low-level output current		8	
Δt/Δv Input transition rise or fall time		20	ns/V
T _A Operating free-air temperature	−40	125	°C

- (1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See TI application report, [Implications of Slow or Floating CMOS Inputs](#) (SCBA004).

4.4 Thermal Information

THERMAL METRIC ⁽¹⁾	SN74AHCT138Q-Q1			UNIT
	BQB (WQFN)	D (SOIC)	PW (TSSOP)	
	16 PINS	16 PINS	16 PINS	
R _{θJA} Junction-to-ambient thermal resistance	105.6	73	135.9	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

4.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	T _A = 25°C			MIN	MAX	UNIT
			MIN	TYP	MAX			
V _{OH}	I _{OH} = -50μA	4.5V	4.4	4.5		4.4		V
	I _{OH} = -8mA		3.94			3.8		
V _{OL}	I _{OL} = 50μA	4.5V			0.1		0.1	V
	I _{OL} = 8mA				0.36		0.5	
I _I	V _I = 5.5V or GND	0 V to 5.5 V			±0.1		± 1	μA
I _{CC}	V _I = V _{CC} or GND, I _O = 0	5.5V			4		40	μA
ΔI _{CC} ¹	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5V			1.35		1.5	mA
C _i	V _I = V _{CC} or GND	5V		2	10			pF

1. This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0V or V_{CC}.

4.6 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 5V ± 0.5V (unless otherwise noted) See [Load Circuit and Voltage Waveforms](#)

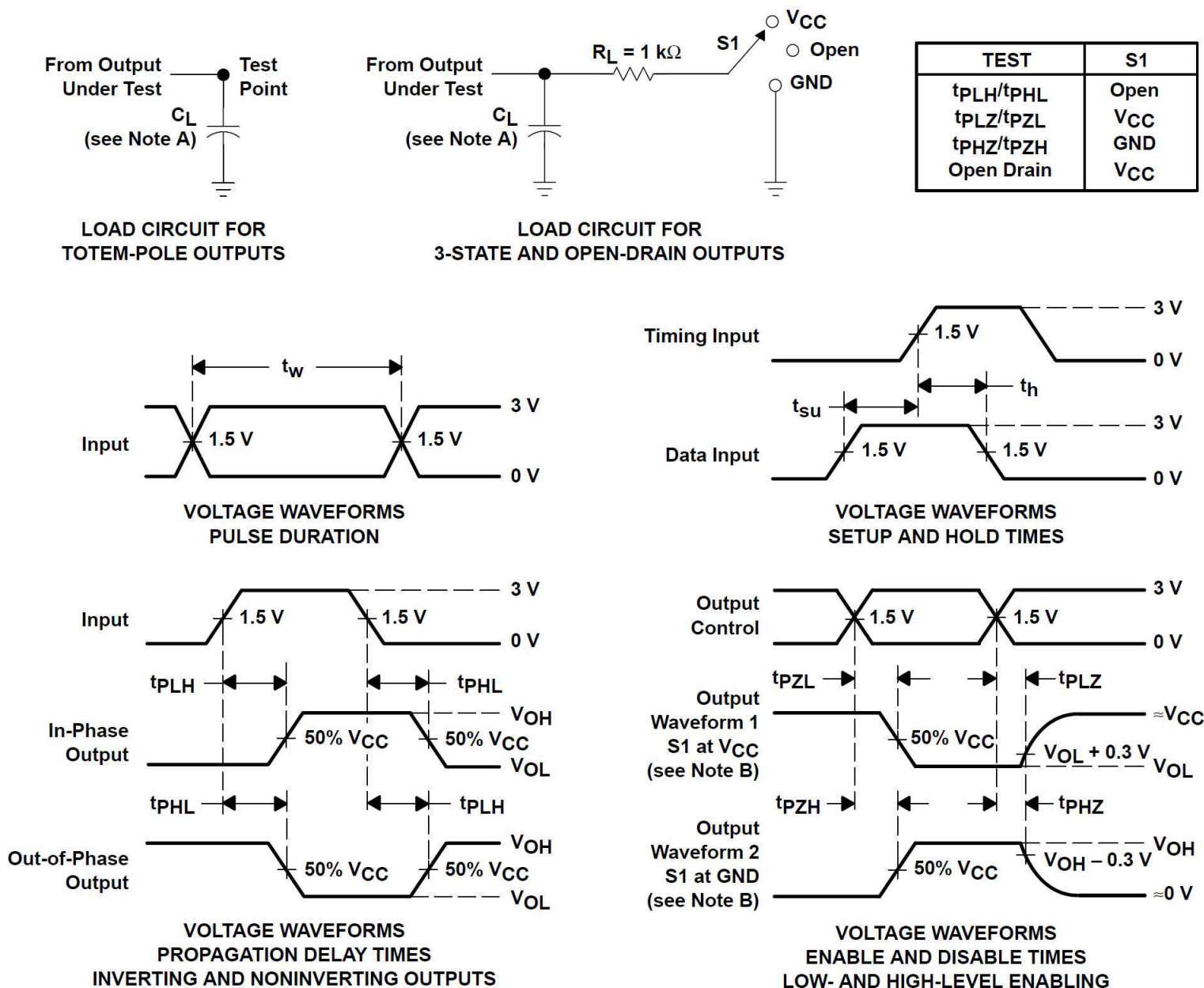
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			MIN	MAX	UNIT
				MIN	TYP	MAX			
t _{PLH}	A, B, C	Any Y	C _L = 15 pF		7.6	10.4	1	12	ns
t _{PHL}					7.6	10.4	1	12	
t _{PLH}	G1	Any Y	C _L = 15 pF		6.6	9.1	1	10.5	ns
t _{PHL}					6.6	9.1	1	10.5	
t _{PLH}	G ₂ A, G ₂ B	Any Y	C _L = 15 pF		7	9.6	1	11	ns
t _{PHL}					7	9.6	1	11	
t _{PLH}	A, B, C	Any Y	C _L = 50 pF		8.1	11.4	1	13	ns
t _{PHL}					8.1	11.4	1	13	
t _{PLH}	G1	Any Y	C _L = 50 pF		7.1	10.1	1	11.5	ns
t _{PHL}					7.1	10.1	1	11.5	
t _{PLH}	G ₂ A, G ₂ B	Any Y	C _L = 50 pF		7.5	10.6	1	12	ns
t _{PHL}					7.5	10.6	1	12	

4.7 Operating Characteristics

V_{CC} = 5V, T_A = 25°C

PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd} Power dissipation capacitance	No load, f = 1MHz	14	pF

5 Parameter Measurement Information



- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
- C. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- D. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1\text{ MHz}$, $Z_O = 50\Omega$, $t_r \leq 3\text{ ns}$, $t_f \leq 3\text{ ns}$.
- E. The outputs are measured one at a time with one input transition per measurement.

Figure 5-1. Load Circuit and Voltage Waveforms

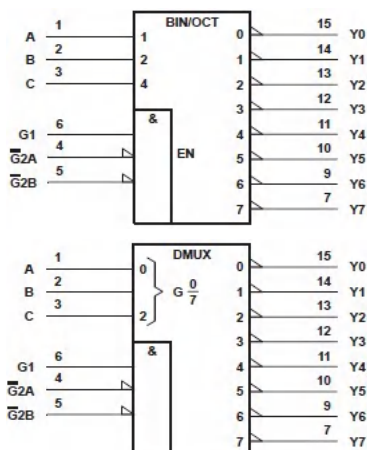
6 Detailed Description

6.1 Overview

The conditions at the binary-select inputs and the three enable inputs select one of eight output lines. Two active-low and one active-high enable inputs reduce the need for external gates or inverters when expanding. A 24-line decoder can be implemented without external inverters and a 32-line decoder requires only one inverter. An enable input can be used as a data input for demultiplexing applications.

6.2 Functional Block Diagram

Logic Symbols (Alternatives)



6.3 Device Functional Modes

Table 6-1. Function Table

INPUTS						OUTPUTS							
ENABLE			SELECT										
G1	G2A	G2B	C	B	A	Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7
X	H	X	X	X	X	H	H	H	H	H	H	H	H
X	X	H	X	X	X	H	H	H	H	H	H	H	H
L	X	X	X	X	X	H	H	H	H	H	H	H	H
H	L	L	L	L	L	L	H	H	H	H	H	H	H
H	L	L	L	L	H	H	L	H	H	H	H	H	H
H	L	L	L	H	L	H	H	L	H	H	H	H	H
H	L	L	L	H	H	H	H	H	L	H	H	H	H
H	L	L	H	L	L	H	H	H	H	L	H	H	H
H	L	L	H	L	H	H	H	H	H	H	L	H	H
H	L	L	H	H	L	H	H	H	H	H	H	L	H
H	L	L	H	H	H	H	H	H	H	H	H	H	L

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

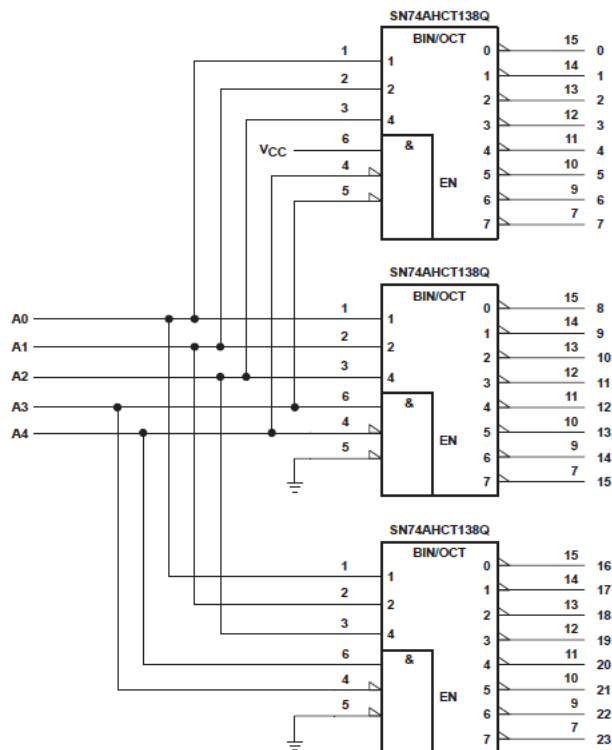


Figure 7-1. 24-Bit Decoding Scheme

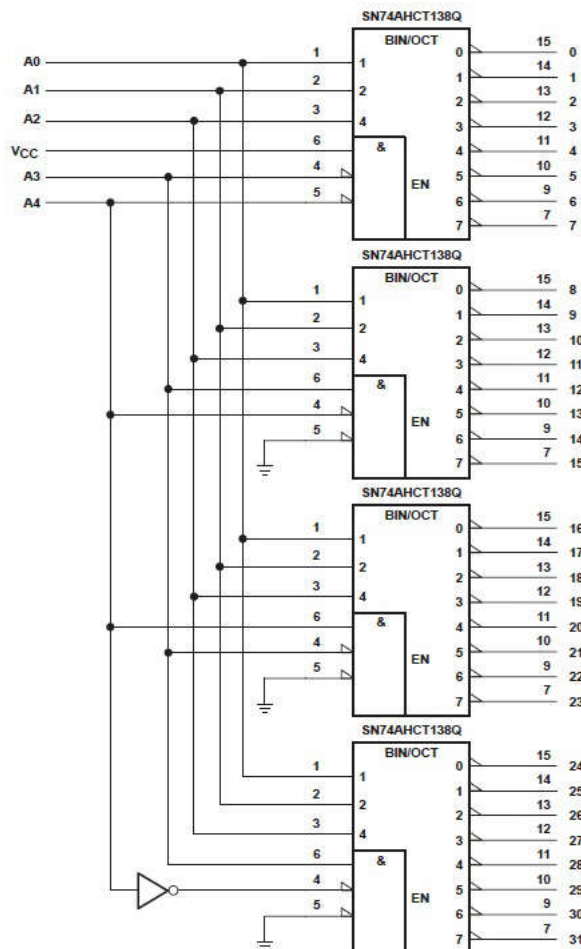


Figure 7-2. 32-Bit Decoding Scheme

7.2 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the [Section 4.3](#).

Each V_{CC} terminal must have a good bypass capacitor to prevent power disturbance. A 0.1 μ F bypass capacitor is recommended to be placed close to the V_{CC} terminal. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise; 0.1 μ F and 1 μ F capacitors are commonly used in parallel. The bypass capacitor must be installed as close to the power terminal as possible for best results.

7.3 Layout

7.3.1 Layout Guidelines

Reflections and matching are closely related to loop antenna theory, but different enough to warrant their own discussion. When a PCB trace turns a corner at a 90° angle, a reflection can occur. This is primarily due to the change of width of the trace. At the apex of the turn, the trace width is increased to 1.414 times its width. This upsets the transmission line characteristics, especially the distributed capacitance and self-inductance of the trace (resulting in the reflection). It is a given that not all PCB traces can be straight, and so they have to turn corners. [Figure 7-3](#) shows progressively better techniques of rounding corners. Only the last example maintains constant trace width and minimizes reflections.

7.3.2 Layout Example

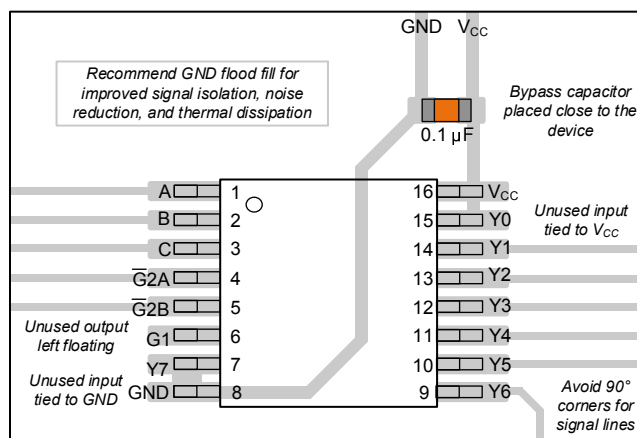


Figure 7-3. Example Layout for the SN74AHCT138Q-Q1

8 Device and Documentation Support

8.1 Documentation Support

8.1.1 Related Documentation

For related documentation see the following:

[Implications of Slow or Floating CMOS Inputs](#) (SCBA004)

8.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN74AHCT138Q-Q1	Click here	Click here	Click here	Click here	Click here

8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.4 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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8.5 Trademarks

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8.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.7 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (February 2002) to Revision B (March 2024)	Page
• Added BQB package to <i>Package Information</i> table, <i>Pin Configuration and Functions</i> , and <i>Thermal Information</i> table.....	1
• Updated thermal value for PW package from RθJA = 108 to 135.9; added RθJC(top), ΨJT, ΨJB, all values in °C/W	5

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CAHCT138QPWRG4Q1	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB138Q	Samples
SN74AHCT138QDRQ1	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT138Q	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CAHCT138QPWRG4Q1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

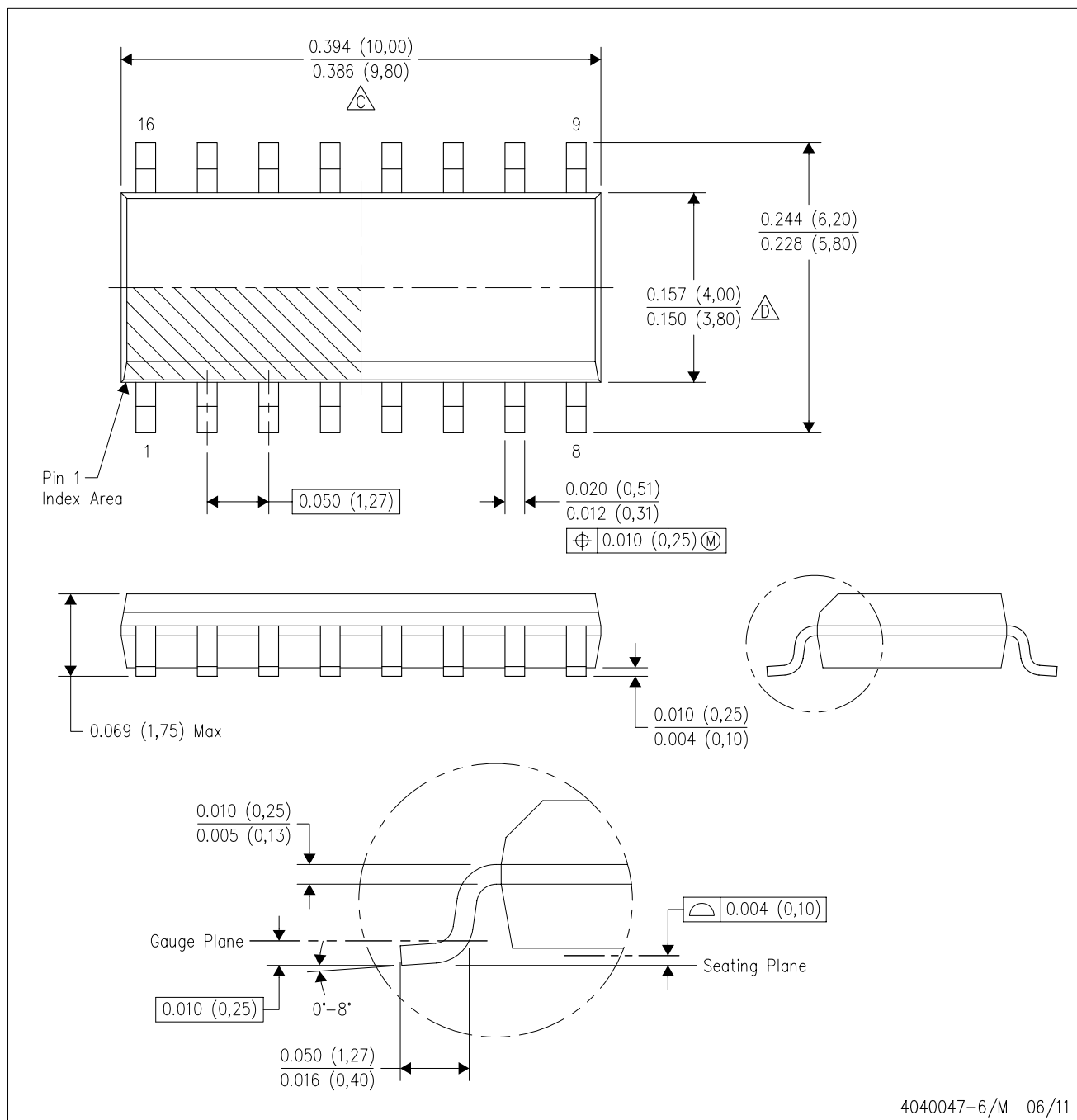


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CAHCT138QPWRG4Q1	TSSOP	PW	16	2000	356.0	356.0	35.0

D (R-PDSO-G16)

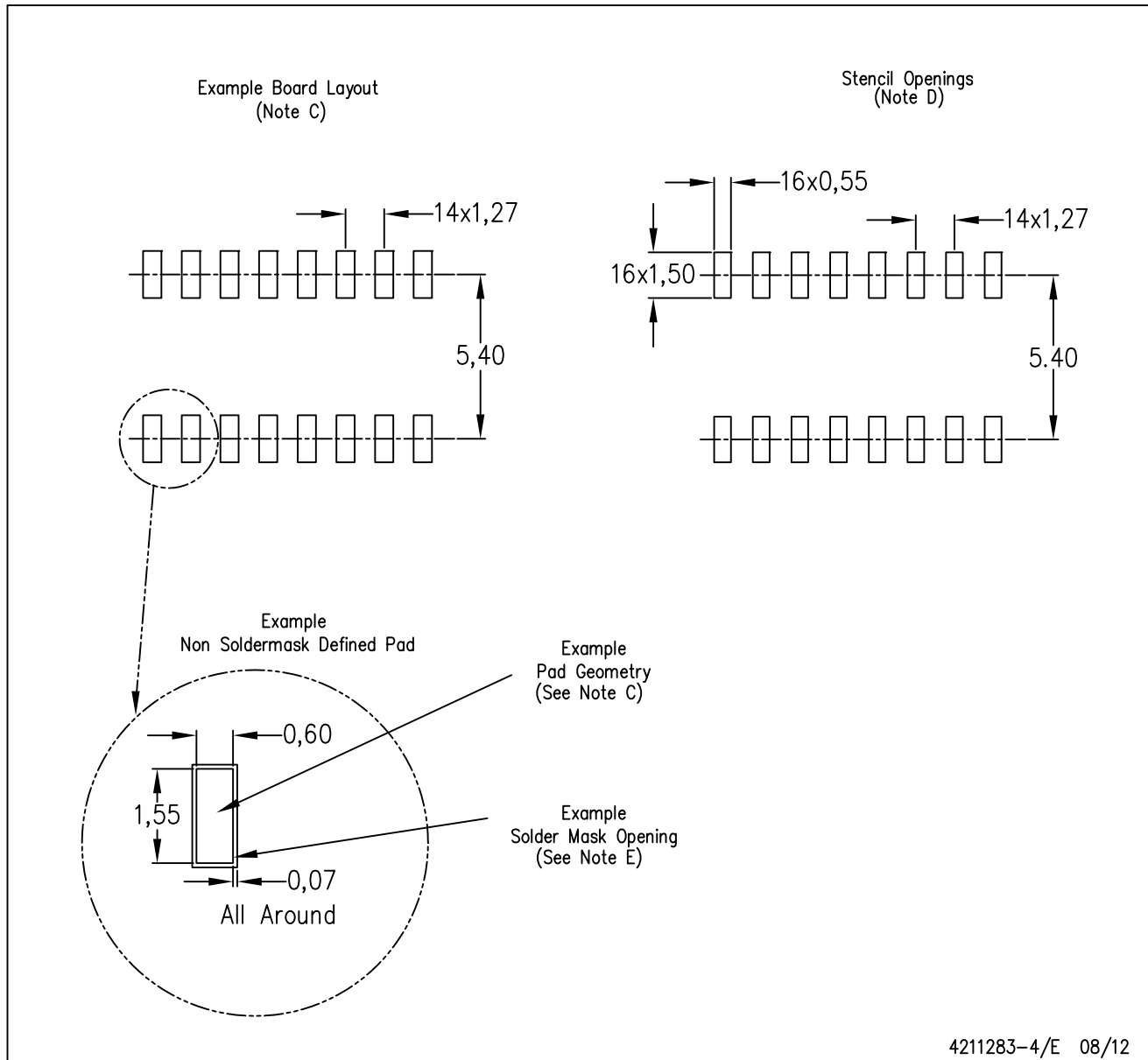
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



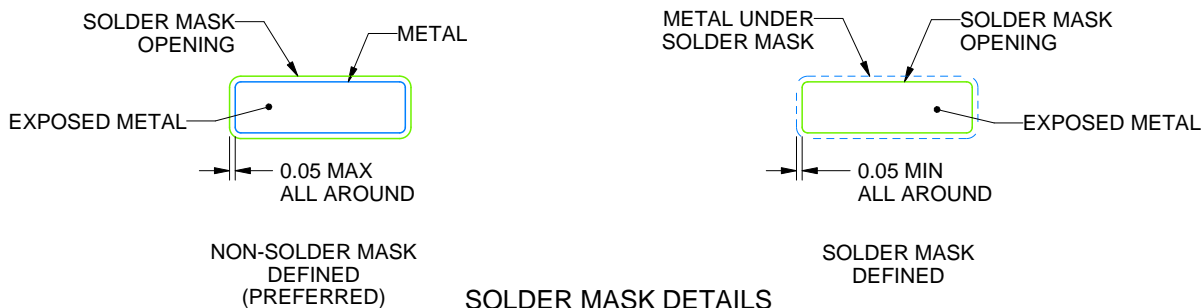
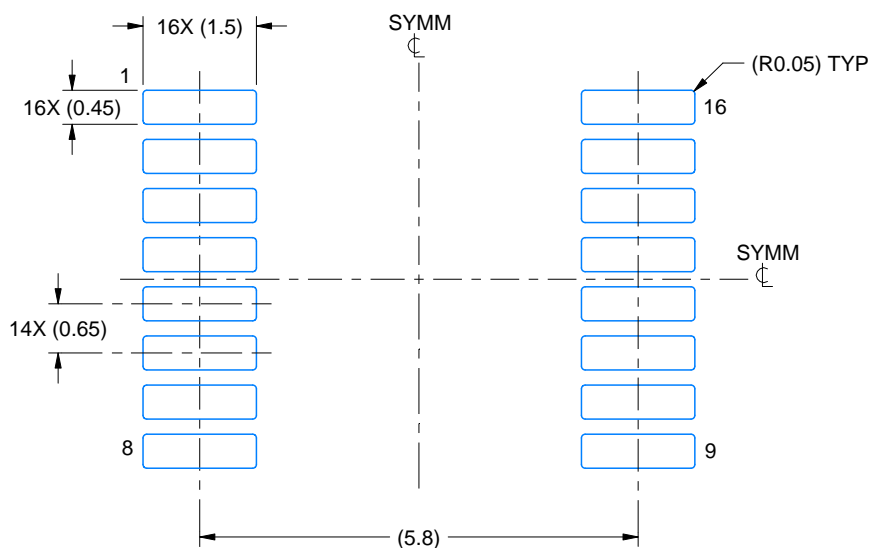
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



4220204/A 02/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

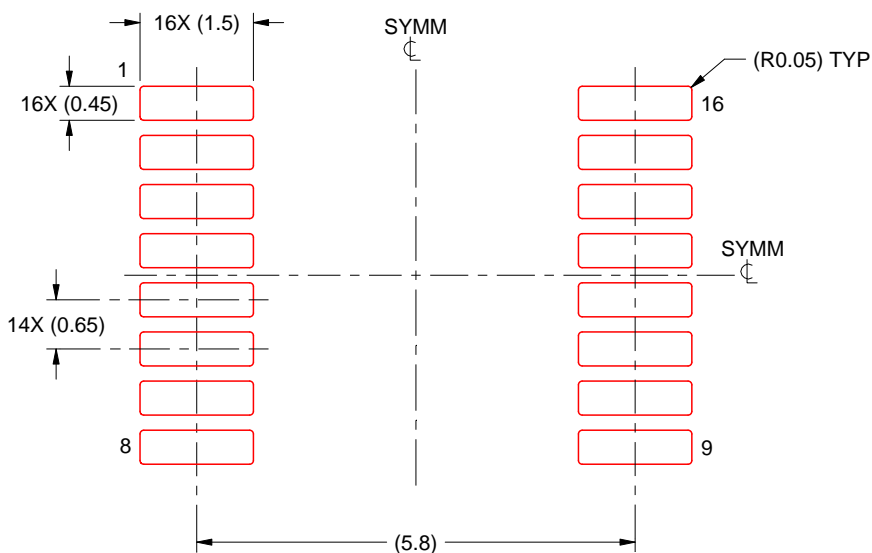
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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